

High Performance Schottky Rectifier 2 x 120A/200V

FEATURES

- 175°C T_J operation
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Extremely low switching losses
- Designed and qualified for industrial level
- International standard package SOT-227
- Low I_{RM} values
- UL approved file E320098 

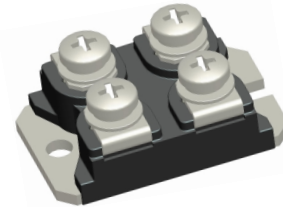
DESCRIPTION

The NST240S200 Schottky rectifier module series has been optimized for low reverse leakage at high temperature.

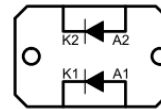
The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature.

TYPICAL APPLICATIONS

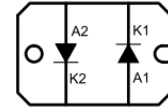
- High current switching power supplies
- Plating power supplies
- UPS system
- Converters
- Freewheeling diode
- Welder
- Reverse battery protection.



CIRCUIT CONFIGURATION



Parallel
NST240S200



Anti-Parallel
NST240S200-A

PRODUCT SUMMARY

I _{F(AV)}	120Ax2
V _R	200V

MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VALUES	UNIT
I _{F(AV)}	Rectangular waveform	120	A
V _{RRM}		200	V
I _{FSM}	t _p = 5 μs sine	10000	A
V _F	120 Apk, T _J = 125°C	0.82	V
T _J	Range	-55 to 175	°C

VOLTAGE RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Maximum DC reverse voltage	V _R	200	V
Maximum working peak reverse voltage	V _{RWM}		

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNIT
Maximum average forward current per leg	I _{F(AV)}	50% duty cycle at T _C = 105°C, rectangular waveform		120	A
Maximum peak one cycle non-repetitive surge current	I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	10000	
		10 ms sine or 6 ms rect. pulse		1400	
Non- repetitive avalanche energy	E _{AS}	T _J = 25°C, I _{AS} = 5.5A, L=1.0mH		15	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μs f = 10 KHz, V _A =1.5xV _R typical		1.0	A

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNIT	
Maximum forward voltage drop per leg	$V_{FM}^{(1)}$	120A	$T_J = 25^{\circ}\text{C}$	0.92	V	
		240A		1.15		
		120A	$T_J = 125^{\circ}\text{C}$	0.82		
		240A		1.10		
Maximum reverse leakage current per leg	$I_{RM}^{(1)}$	$T_J = 25^{\circ}\text{C}$	$V_R = \text{Rated } V_R$	10	μA	
		$T_J = 125^{\circ}\text{C}$		10	mA	
Maximum junction capacitance per leg	C_T	$V_R = 5\text{ V}_{DC}$ (test signal range 100 kHz to 1 MHz) 25°C		3000	pF	
Typical series inductance per leg	L_S	From top of terminal hole to mounting plane		6	nH	
Maximum voltage rate of change	dv/dt	Rated V_R		10000	V/ μs	
Maximum RMS insulation voltage	V_{INS}	50/60Hz, $I_{INS} < 1\text{mA}$		2500 (1 min) 3000 (1 s)	V	

Note

(1) Pulse width < 500 μs , duty cycle < 2%

THERMAL-MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT
Maximum junction and storage temperature range	T _J , T _{stg}	-55	-	175	°C
Thermal resistance, junction to case	R _{thJC}	-	-	0.34	°C/W
Thermal resistance, case to heatsink	R _{thCS}	-	0.10	-	
Weight		-	30 (1.06)	-	g(oz.)
Mounting torque, ± 10% to heatsink, M4 busbar, M4		-	1.1 (9.7)	-	N•m (lbf • in)
		-	1.1 (9.7)	-	
Case style	JEDEC SOT-227 module (insulated)				

Ordering Information Tabel

Device code	N	ST	240	S	200	—	A
	①	②	③	④	⑤		⑥

- ① - Nell's high power module
- ② - Package indicator, "ST" for SOT-227
- ③ - Maximum average forward current, 240 = 120A x 2
- ④ - S = Schottky family
- ⑤ - Voltage rating (200 = 200V)
- ⑥ - Circuit type, A for Anti-Parallel type
Blank for Parallel type

Fig.1 Maximum forward voltage drop characteristics

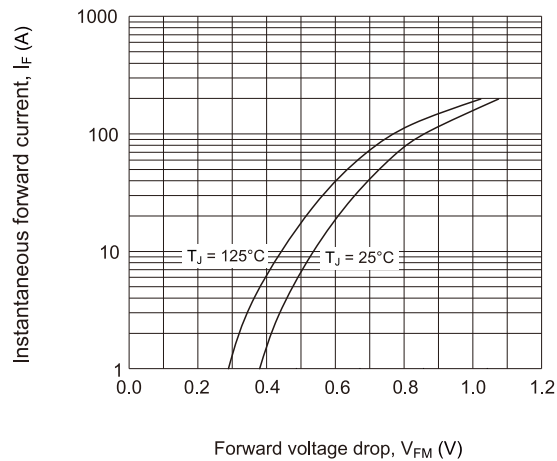


Fig.2 Maximum values of reverse current vs. reverse voltage

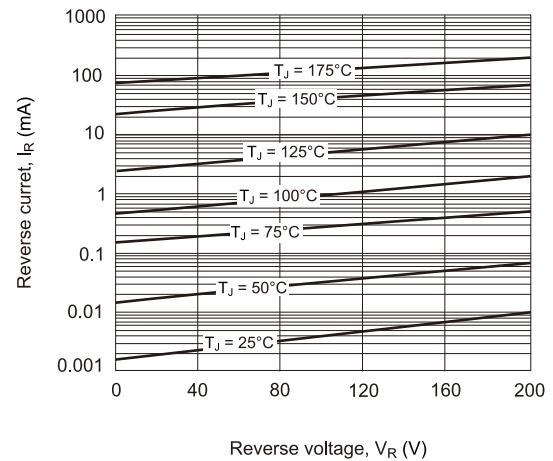


Fig.3 Maximum thermal impedance $R_{th(j-c)}$ characteristics

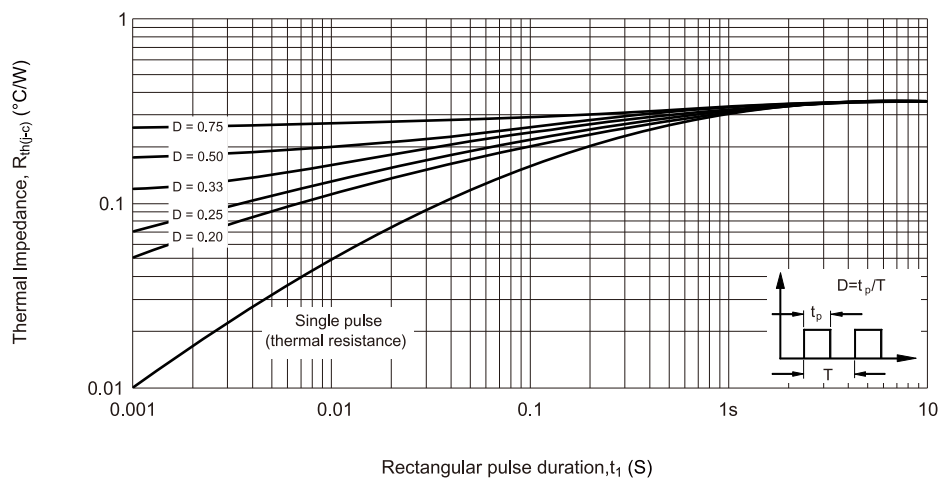


Fig.4 Typical junction capacitance vs. reverse voltage

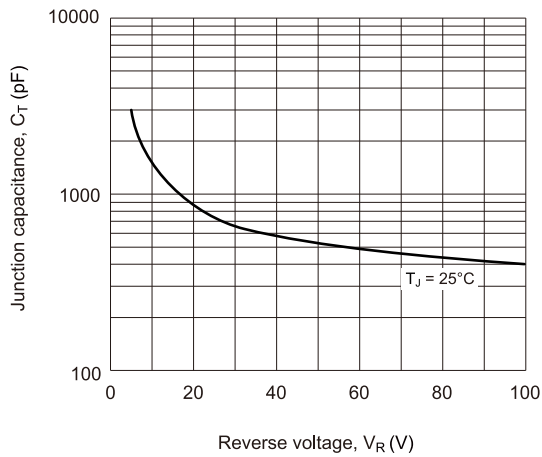


Fig.5 Maximum allowable case temperature vs. Average forward current

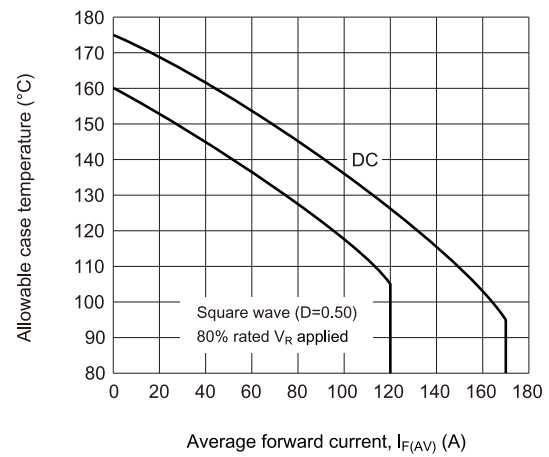


Fig.6 Forward power loss characteristics

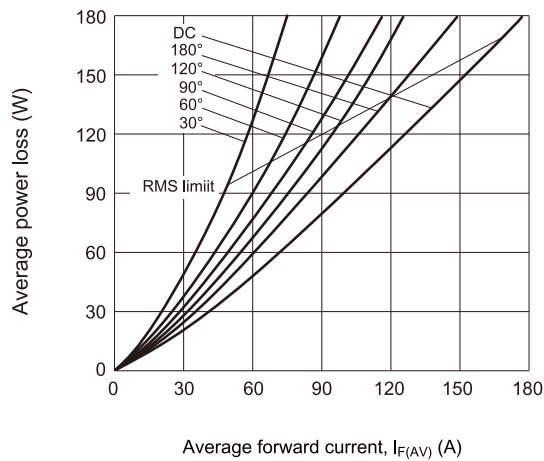
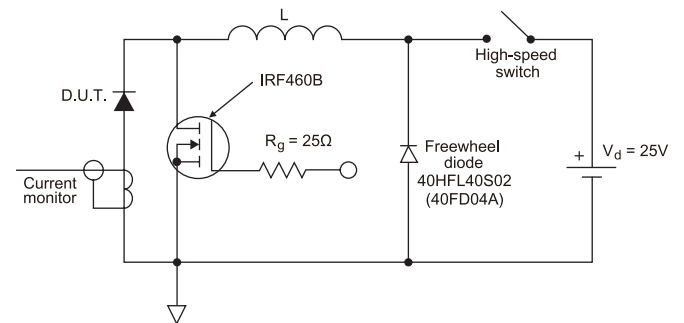


Fig.7 Unclamped Inductive test circuit



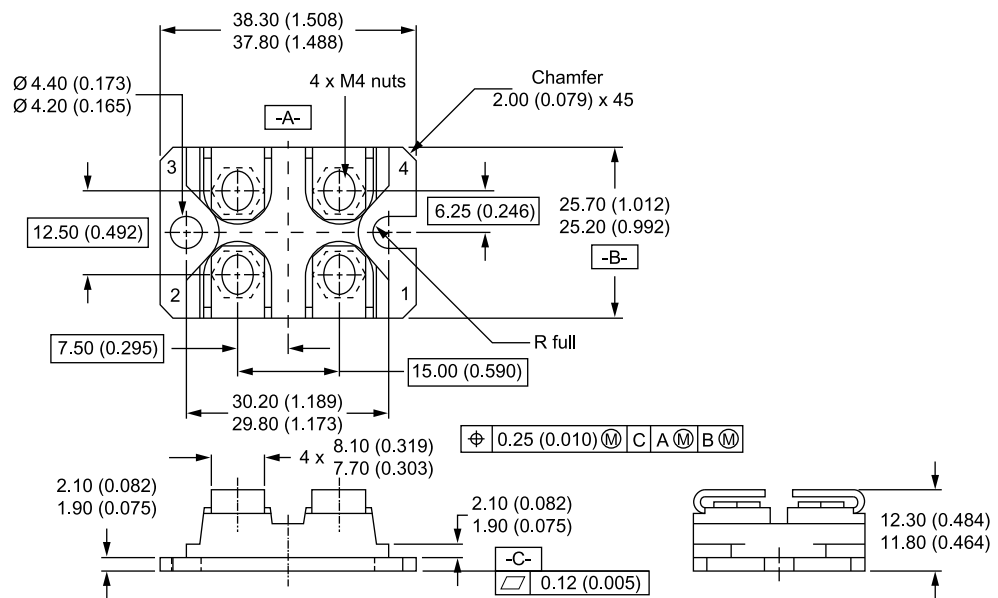
Note

(1) Formula used: $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$;

P_d = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig.6)

P_{dREV} = Inverse power loss = $V_{R1} \times I_R (1-D)$; I_R at V_{R1} = rated V_R

SOT-227



All dimensions in millimeters (inches)

Notes

- Dimensioning and tolerancing per ANSI Y14.5M-1982
- Controlling dimension: millimeter